

9.0 x 7.0 x 2.24 mm

ASGTX



(Pb) RoHS/RoHS II Compliant

▷ OVERVIEW:

ASGTX temperature compensated Crystal Oscillators are designed to accommodate a broad breadth of Precision TCXO requirements, without NRE and extended lead-times. This oscillator series is designed and manufactured by Abracon Corporation and is available to order from 1pc to high volume production quantities.

• 1-5 day quick-turn availability of a TCXO/VCTCXO with LVCMOS output, <u>Any frequency</u> between 10MHz & 250MHz

For example, if a reference oscillator requirement calls out 49.7521MHz; ± 1.00 ppm TCXO/VCTCXO with **LVCMOS** output, ASGTX can be configured and shipped within 1-5 days and in most cases, same day if order is received before noon. Customers with low-to-mid annual volume requirements find it difficult to procure custom frequency TCXO/VCTXCO's without costly NRE charges and/or long lead-times (≥ 12 weeks).

• 1-5 day quick turn availability of a TCXO/VCTXCO requiring LVDS or LVPECL Differential output, <u>Any frequency</u> between 10MHz to 1.50GHz

ASGTX is available with either **LVDS or LVPECL** output, from **10MHz to 1.50GHz**; at any desired frequency, such as 149.875MHz, 1.00GHz, 1.5GHz, etc. with as tight as \pm 1.00 ppm stability over temperature. No other solution in the marketplace currently offers such capability, especially in a small form-factor of 9.0x7.0x2.24 mm.

ASGTX is suitable for a wide variety of precision timing applications where TCXO/VCTXO's are typically employed. In addition, for high frequency LO requirements, traditionally customers have relied on SAW based oscillators. Such devices are only available at a few fixed frequencies, such as 915MHz, 1.0GHz, etc. They are typically in 9x14mm or bigger packages and vary as much as ± 100 ppm over temperature.

Although ASGTX series will be slightly less favorable in phase noise performance compared to SAW based oscillators, it offers the following key advantages:

- o ± 1.00 ppm stability over -30°C to +70°C & ± 2.00 ppm stability over -40°C to +85°C
- o Any carrier frequency between 10MHz & 1.50GHz
- o LVCMOS Output (10MHz to 250MHz) or LVDS / LVPECL Output (10MHz to 1.50GHz)
- o Small form-factor of 9.0x7.0x2.24 mm
- o No NRE or lead-time

FEATURES:

ABRACON IS ISO9001:2008

CERTIFIED

- 10MHz to 1.50GHz, any Carrier Frequency in differential mode (LVDS or LVPECL)
- 10MHz to 250MHz, any Carrier Frequency in LVCMOS mode
- -40°C to +85°C operating temperature range
- ± 1.0 ppm stability over -30°C to +70°C and ± 2.0 ppm stability over -40°C to +85°C
- Minimum guaranteed pull ability of \pm 10ppm in VCTCXO mode
- · Good Phase Noise, excellent Harmonics and Spurious content
- Guaranteed rms jitter of 1.80ps maximum @ 1.50GHz carrier (LVDS mode)
- Immediate availability, 5-day maximum lead-time for small quantities



▷ APPLICATIONS:

- 40G & 100G Ethernet
- WiMax,
- LTE, BTS
- CATV, LAN, LMDS
- Point-to-Point communication networks



ASGTX

(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

KEY ELECTRICAL SPECIFICATIONS:

Parameters		Minimum	Typical	Maximum	Units	Notes
	LVCMOS	10		250	MHz	
Frequency:	LVDS	10		1500		
	LVPECL	10		1500		
Operating Tempera	ature:	-40		+85	°C	
Storage Temperatu	re:	-40		+85	°C	
Frequency Stability	/:			_		
Initial Set Tole	rance	-1.50	$\leq \pm 1.00$	+1.50	ppm	1 hour after reflow
Stability over operating temperature*	-30°C to +70°C	-1.00		+1.00	ppm	Option "1"
	-40°C to +85°C **	-2.00		+2.00		Option "2"
Aging @ 25°C after one year		-1.00		+1.00	ppm	
Supply Voltage (Vdd):		3.135	3.300	3.465	V	
Startup Time:				3	ms	
Control Voltage***:		0		Vdd	V	In VCTCVO Mada
Frequency Pull:		±10			ppm	III VCICAO Mode
Phase jitter RMS [tjit()] **** (12kHz to 20MHz)			<1.00	1.80	ps	Frequency dependent

Notes

* **Relative to measured frequency post reflow**

** Please contact Abracon for ±1.00 ppm frequency stability over -40°C to +85°C

*** Center Control Voltage value is either 1.28V ±0.20V or, 1.55V ±0.20V for the device to be with-in ±1.50 ppm of final frequency, 1-hour post reflow

**** 1.8ps max is guaranteed for LVCMOS and LVDS output modes. For LVPECL mode at carrier frequency greater than 1.289GHz, the maximum RMS jitter is 3.0ps

Key Electrical Specifications – LVCMOS

Parameters		Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd}):				45	mA	Frequency dependent
Output Load:				15	pF	
Output Logio Logio!	V _{OH}	0.9*V _{dd}			V	
Output Logic Level.	V _{OL}			$0.1*V_{dd}$	V	
Rise Time (Tr):				1000	ps	
Fall Time (Tf):				1000	ps	
Duty Cycle:		45		55	%	@1/2Vdd







ASGTX

(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

Key Electrical Specifications – LVPECL

Parameters		Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd})				60	mA	With typical LVPECL output termination
Output Logic Loval	V _{OH}	V _{dd} -1.03		V _{dd} -0.60	V	
Output Logic Level	V _{OL}	V _{dd} -1.85		V _{dd} -1.60	V	
Rise Time (Tr):				350	ps	
Fall Time (Tf):				350	ps	
Differential Duty Cycle:		45		55	%	DODC _{LVPECL}

Key Electrical Specifications – LVDS

Parameters	Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd})			40	mA	With typical LVDS output termination
Differential Output Voltage (V _{OD})	175	350		mV	
V_{OD} Magnitude Change (ΔV_{OD})			50	mV	
Offset Voltage (V _{OS})		1.25		V	
V_{OS} Magnitude Change (ΔV_{OS})			50	mV	
Rise Time (Tr):			350	ps	
Fall Time (Tf):			450	ps	
Differential Duty Cycle:	45		55	%	ODC _{LVDS}

OPTIONS & PART IDENTIFICATION:









(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

ASGTX



ABRACON IS ISO9001:2008 CERTIFIED





(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

ASGTX



With LVCMOS Output; 120MHz Carrier



With LVDS Output; 50MHz Carrier Agilent E5052A Signal Source Analyzer & E5053A Microwave Downconverter 12KHz to 10MHz hase Noise 10.00dB/ Ref 10.00dBc/H: 100082 20.00 r 50.00082 MHz 3.. -70.0034 dBc/Hz -98.3781 dBc/Hz -121.5073 dBc/Hz -128.7270 dBc/Hz -130.5513 dBc/Hz -148.9764 dBc/Hz -154.5722 dBc/Hz -154.3711 dBc/Hz 10 Hz 100 Hz 1 kHz 10 kHz 100 kHz 1 MHz 5 MHz 10 MHz 10.00 2:34:567: 0.000 -10.00 -20,00 >8 X8: 10 MHZ -158,3111 dBc/H Noise -Analysis Range X: Band Marker Analysis Range Y: Band Marker Intg Noise: -75,3595 dBc / 9.5 RMS Noise: 241.29 µrad 13.8249 mdeg RMS Jitter: 768.049 fsec Residual FM: 405,245 Hz -30.00 -40.00 9,988 MHz -50.00 -60,00 -70,00 -80,00 -90.00 -100.0 -110.0 -120.0 -130.0 -140.0 -150.0 Å -160.0 -170.0 -180.0 IF Gain 20dB 775pts Opt [Phase Noise Start 10 Hz Stop 10 MHz 16/16 Atte OdP

With LVPECL Output; 500MHz Carrier



ABRACON IS ISO9001:2008 CERTIFIED





(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

ASGTX





With LVDS Output; 1.50GHz Carrier



Carrier	RF Output	rms Phase Jitter	Integration Bandwidth
10.00MHz	LVDS	992 fs	12kHz to 5MHz
25.00MHz	LVDS	774 fs	12kHz to 5MHz
50.00MHz	LVDS	768 fs	12kHz to 10MHz
120.00MHz	LVCMOS	1.1 ps	12kHz to 20MHz
500.00MHz	LVPECL	956 fs	12kHz to 20MHz
1.00GHz	LVDS	911 fs	12kHz to 20MHz
1.2890625GHz	LVDS	1.03 ps	12kHz to 20MHz
1.50GHz	LVDS	1.55 ps	12kHz to 20MHz

ABRACON IS ISO9001:2008 CERTIFIED





ASGTX

(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm





FREQUENCY PULL VS. CONTROL VOLTAGE (VCTCXO MODE)







(Pb) RoHS/RoHS II Compliant

OUTLINE DIMENSION:

ASGTX

LVCMOS output 0.354 9.00 5 6 4 0.276 asgtx 2 3 0.088 Pin # 1 Identifier 0.102 0.047 2.60 1.20 TYP 3 1 2 0.122 3.10 v¢ GND NC FSELI FSELO PROG



D • //	Pin Description				
Pin #	ТСХО	VCTCXO			
1	N/C ⁽¹⁾				
2	By-Pass ⁽²⁾	Vc ⁽³⁾			
3	GND				
4	RF Output				
5	N/C ^(Î)				
6	Vdd				

N/C⁽¹⁾ = Please leave these pins electrically floating on the end-PCB

By-Pass $^{(2)}$ = In TCXO configuration, it is recommended that a 1,000pF COG by-pass capacitor is connected between Pin#2 and GND

 $\mathbf{Vc}^{(3)} =$ Please connect external voltage to pull the oscillator frequency



Dimensions: inches [mm]





ASGTX

(Pb) RoHS/RoHS II Compliant



9.0 x 7.0 x 2.24 mm





D:n #	Pin Description				
F III #	ТСХО	VCTCXO			
1	N/C ⁽¹⁾				
2	By-Pass ⁽²⁾	Vc ⁽³⁾			
3	GND				
4	RF Output				
5	Complimentary RF Output				
6	Vdd				

N/C⁽¹⁾ = Please leave this pin electrically floating on the end-PCB

By-Pass $^{(2)}$ = In TCXO configuration, it is recommended that a 1,000pF COG by-pass capacitor is connected between Pin#2 and GND

Vc $^{(3)}$ = Please connect external voltage to pull the oscillator frequency



Recommended Land Pattern

Dimensions: inches [mm]







(Pb) RoHS/RoHS II Compliant

9.0 x 7.0 x 2.24 mm

REFLOW PROFILE:

ASGTX





ATTENTION: Abracon Corporation's products are COTS – Commercial-Off-The-Shelf products; suitable for Commercial, Industrial and, where designated, Automotive Applications. Abracon's products are not specifically designed for Military, Aviation, Aerospace, Life-dependant Medical applications or any application requiring high reliability where component failure could result in loss of life and/or property. For applications requiring high reliability and/or presenting an extreme operating environment, written consent and authorization from Abracon Corporation is required. Please contact Abracon Corporation for more information.

ABRACON IS ISO9001:2008 CERTIFIED



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Programmable Oscillators category:

Click to view products by ABRACON manufacturer:

Other Similar products are found below :

8N4Q001LG-0102CDI 8N4Q001LG-0139CDI DSC8101AL2 8N0Q001BH-2202CDI DSC8101DI5 DSC8121AI5 EP16E7E2H26.000MTR SIT8102AI-13-18E-25.00000T 8N4Q001LG-1033CDI DSC8121CL5T DS1090U-2/V+T DS1090U-32+T DSC8121AM2 DSC8001AL2 DSC8101BL2 DSC8121CI1 DSC8124CI5 DSC8003CI2T DSC8102DI2 DSC8124CI2 DSC8123CI5 DSC8124BI2 DSC8122BI5 DSC8101DI2 DSC8121CL5 SG-8002JA 20.000M-PTMB-ROHS ECS-P143-10-AN 570FCC001204DG 570FCC000169DG 544BAEB002025CBG 544BAHB002172BBGR 544BAHB002157BBGR DS1077LU-40+T SiT3808AI-D2-XXXX-000.FP000X DS1090U-1+T DS1086Z+T&R DS1087LU-447+T 544BCAA000112BBG DS1086LU+T 564BACA001478ABG SG-8002CA 2.4576M-PCBB 564BACA000121ABG 564BACA001478BBG 564BABA002053ABG 564BAAA000121ABG 564BAAC000115BBG 564BAAD000115BBG ECS-P8F3X-1.000-AN 570CBC000306DG SiT8008AC-33-18E-33.33330